

SCHOTTKY RECTIFIER
HIGH EFFICIENCY SERIES

16SCYQ030C

16 Amp, 30V

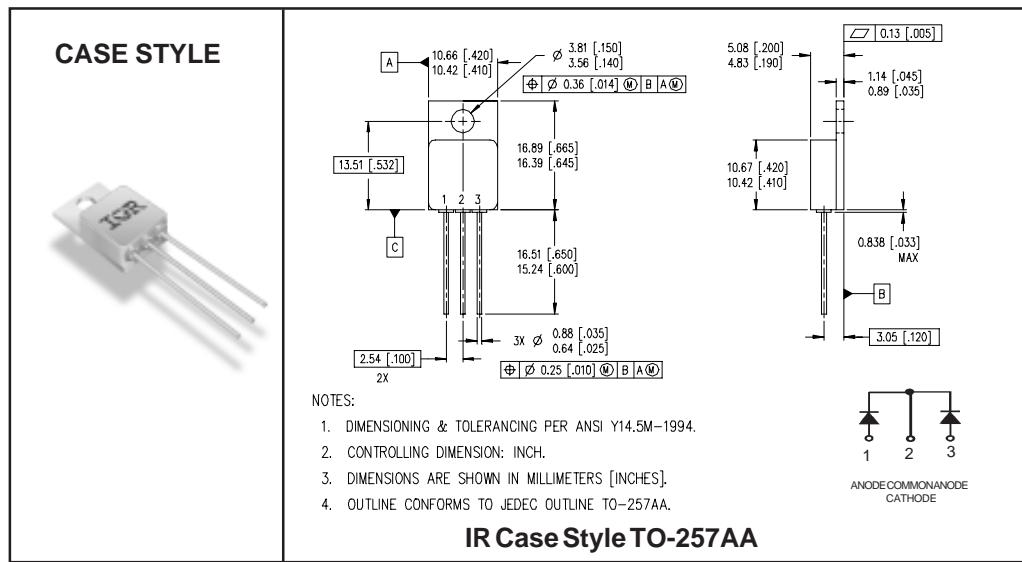
Major Ratings and Characteristics

Characteristics	16SCYQ030C	Units
I _{F(AV)}	16	A
V _{RRM} (Per Leg)	30	V
I _{FSM} @ t _p = 8.3ms half-sine (Per Leg)	150	A
V _F @ 15Apk, T _J = 125°C (Per Leg)	0.48	V
T _J , T _{stg} Operating and storage	-55 to 150	°C

Description/Features

The 16SCYQ030C center tap Schottky rectifier has been expressly designed to meet the rigorous requirements of hi-rel environments. It is packaged in the hermetic isolated TO-257AA package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source control drawings to TX, TXV and S quality levels.

- Hermetically Sealed
- Ceramic Eyelets
- Low Forward Voltage Drop
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long term Reliability
- Lightweight



Voltage Ratings

Part number	16SCYQ030C		
V_R Max. DC Reverse Voltage (V) (Per Leg)	30		
V_{RWM} Max. Working Peak Reverse Voltage (V) (Per Leg)			

Absolute Maximum Ratings

Parameters	Limits	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current See Fig. 5	16	A	50% duty cycle @ $T_C = 138^\circ\text{C}$, square waveform
I_{FSM} Max. Peak One Cycle Non - Repetitive Surge Current (Per Leg)	150	A	@ $t_p = 8.3$ ms half-sine

Electrical Specifications

Parameters	Limits	Units	Conditions		
V_{FM} Max. Forward Voltage Drop (Per Leg) See Fig. 1①	0.57	V	@ 7.5A	$T_J = -55^\circ\text{C}$ ②	
	0.65	V			
	0.66	V			
	0.48	V			
	0.58	V	@ 15A	$T_J = 25^\circ\text{C}$ ②	
	0.60	V			
	0.33	V	@ 16A	$T_J = 125^\circ\text{C}$ ②	
	0.48	V			
I_{RM} Max. Reverse Leakage Current (Per Leg) See Fig. 2①	1.0	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$ ②	
	117	mA			
	150	mA			
C_T Max. Junction Capacitance (Per Leg)	1900	pF	$V_R = 5\text{V}_{\text{DC}}$ (1MHz, 25°C) ②		
L_s Typical Series Inductance (Per Leg)	6.9	nH	Measured from anode lead to cathode lead 6mm (0.025 in.) from package		

Thermal-Mechanical Specifications

Parameters	Limits	Units	Conditions	
T_J Max.Junction Temperature Range	-55 to 150	°C		
T_{stg} Max. Storage Temperature Range	-55 to 150	°C		
R_{thJC} Max. Thermal Resistance, Junction to Case (Per Leg)	1.6	°C/W	DCoperation	See Fig. 4
R_{thJC} Max. Thermal Resistance, Junction to Case (Per Package)	0.8	°C/W	DCoperation	
w_t Weight (Typical)	4.3	g		
Die Size (Typical)	115X170	mils		
Case Style	TO-257AA			

① Pulse Width < 300μs, Duty Cycle < 2%

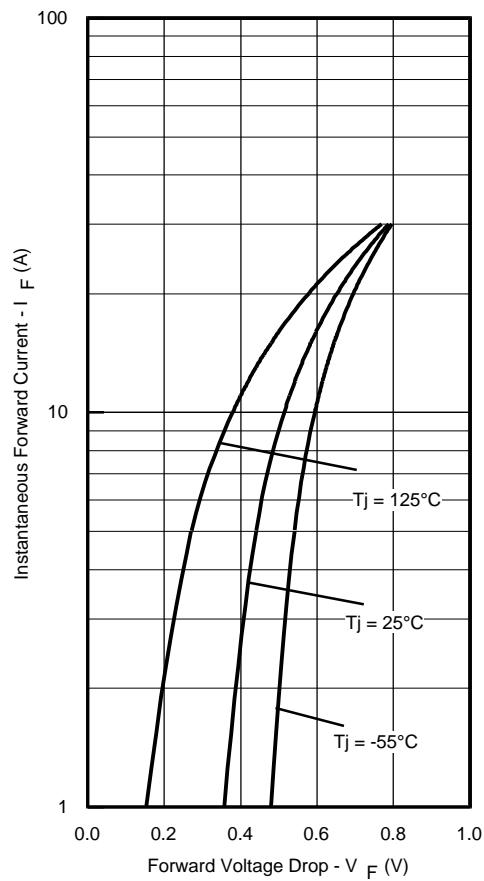


Fig. 1 - Max. Forward Voltage Drop Characteristics
 (Per Leg)

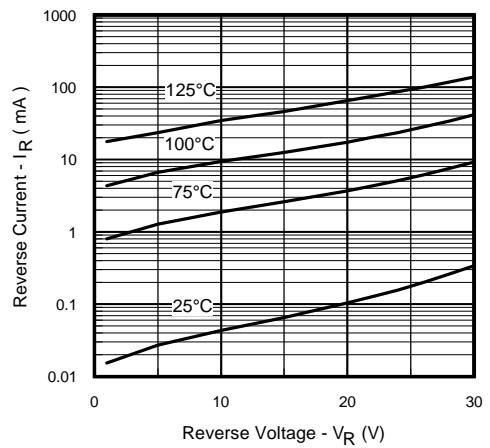


Fig. 2 - Typical Values of Reverse Current
 Vs. Reverse Voltage (Per Leg)

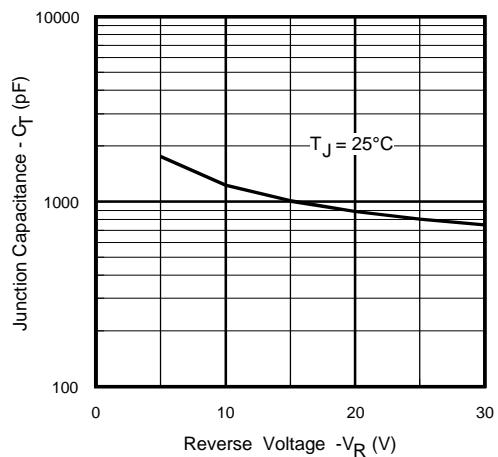


Fig. 3 - Typical Junction Capacitance Vs.
 Reverse Voltage (Per Leg)

16SCYQ030C

International
IR Rectifier

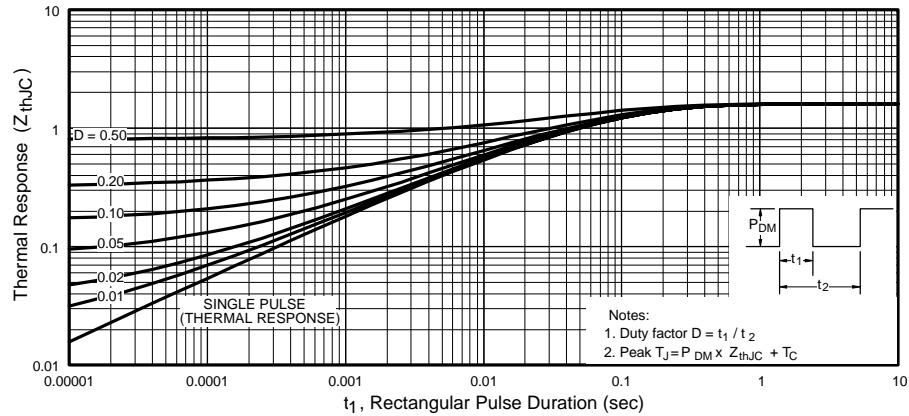


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

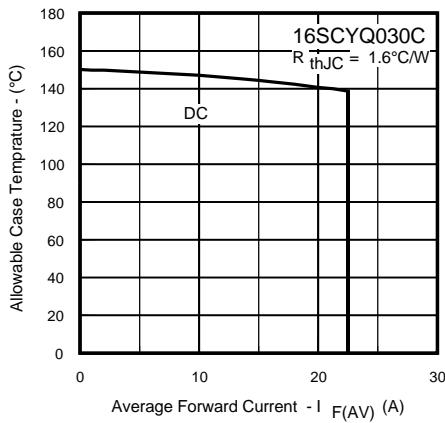


Fig. 5 - Max. Allowable Case Temperature Vs.
Average Forward Current (Per Leg)

International
IR Rectifier

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Data and specifications subject to change without notice. 10/00